Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.380 inches

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.187 inches

Thread Size:

0.112 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 reverse voltage, peak

Current Rating Per Characteristic:

10.00 amperes forward current, average

Power Rating Per Characteristic:

10.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Thread Series Designator:

Unc

Terminal Type And Quantity:

1 threaded stud and 1 turret

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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